MAX6630MUT Rev. A

**RELIABILITY REPORT** 

FOR

# MAX6630MUT

PLASTIC ENCAPSULATED DEVICES

May 19, 2003

# **MAXIM INTEGRATED PRODUCTS**

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## Conclusion

The MAX6630 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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# I. Device Description

The MAX6630 is a local digital temperature sensor with an SPI<sup>™</sup>-compatible serial interface. The temperature is converted to a 12-bit + sign word with a resolution of 0.0625°C/LSB. An extended temperature range provides useful readings up to +150°C.

This sensor is a 3-wire serial interface SPI compatible, allowing the MAX6630 to be readily connected to a variety of microcontrollers ( $\mu$ Cs). The MAX6630 is a read-only device, simplifying its use in systems where only temperature data is required.

This digital temperature sensor requires very little supply current, making it ideal for portable systems. The MAX6630 performs a conversion once every 0.5s and requirse only 200µA (typ) supply current. This temperature sensor can perform conversions more often—up to approximately four conversions per second by reading the conversion results more often.

#### B. Absolute Maximum Ratings

ltem	Rating	
All Voltages Referenced to GND		
VCC	-0.3V, +6.0V	
SO, SCK, CS	-0.3V, VCC + 0.3V	
SO	-1mA to +50mA	
Current into Any Pin	10mA	
Junction Temperature.	+150°C	
Operating Temperature Range (Note 1)	-55°C to +150°C	
Storage Temperature Range	-65°C to +150°C	
Lead Temperature	Note 2	
Continuous Power Dissipation (TA = +70°C)		
6-Lead SOT23	727mW	
Derates above +70°C		
6-Lead SOT23	91.0mW/°C	

**Note 1:** It is not recommended to operate the device above +125°C for extended periods of time. **Note 2:** This device is constructed using a unique set of packaging techniques that impose a limit on the thermal profile the device can be exposed to during board-level solder attach and rework. This limit permits only the use of the solder profiles recommended in the industry-standard specification, JEDEC 020A, paragraph 7.6, Table 3 for IR/VPR and Convection Reflow. Preheating is required. Hand or wave soldering is not allowed.

# II. Manufacturing Information

A. Description/Function:	12-Bit + Sign Digital Temperature Sensor with Serial Interface
B. Process:	B8
C. Number of Device Transistors:	6475
D. Fabrication Location:	California, USA
E. Assembly Location:	Malaysia
F. Date of Initial Production:	January, 2003

# **III.** Packaging Information

A.	Package Type:	6-Lead SOT23 (Flip-Chip)
В.	Lead Frame:	Copper
C.	Lead Finish:	Solder Plate
D.	Die Attach:	N/A
E.	Bondwire:	6.0 mil dia. Solder-ball
F.	Mold Material:	Epoxy with silica filler
G.	Assembly Diagram:	Buildsheet # 05-2901-0007
H.	Flammability Rating:	Class UL94-V0
l.	Classification of Moisture Sensitivity per JEDEC standard JESD22-A112:	Level 1
IV. Die In	formation	
Α.	Dimensions:	45 x 90 mils
В.	Passivation:	$Si_3N_4/SiO_2$ (Silicon nitride/ Silicon dioxide)
C.	Interconnect:	Aluminum/Copper/Silicon
D.	Backside Metallization:	None
E.	Minimum Metal Width:	.8 microns (as drawn)
F.	Minimum Metal Spacing:	.8 microns (as drawn)
G.	Bondpad Dimensions:	5 mil. Sq.

- H. Isolation Dielectric: SiO<sub>2</sub>
- I. Die Separation Method: Wafer Saw

# V. Quality Assurance Information

A. Quality Assurance Contacts:

Jim Pedicord(Manager, Reliability Operations)Bryan Preeshl(Executive Director of QA)Kenneth Huening(Vice President)

- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

#### VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = 13.57 \times 10^{-9}$$
  $\lambda = 13.57$  F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure the reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on lots exceeding this level. The following Burn-In Schematic (Spec. #06-5653) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

## C. E.S.D. and Latch-Up Testing

The TS03-2 die type has been found to have all pins able to withstand a transient pulse of +/-600V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of  $\pm$ 50mA.

# Table 1 Reliability Evaluation Test Results

# MAX6630MUT

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Tes	t (Note 1)			
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	80	0
Moisture Testi	ng (Note 2)			
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	77	0
Mechanical St	ress (Note 2)			
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters	77	0

Note 1: Life Test Data may represent plastic D.I.P. qualification lots. Note 2: Generic package/process data

# Attachment #1

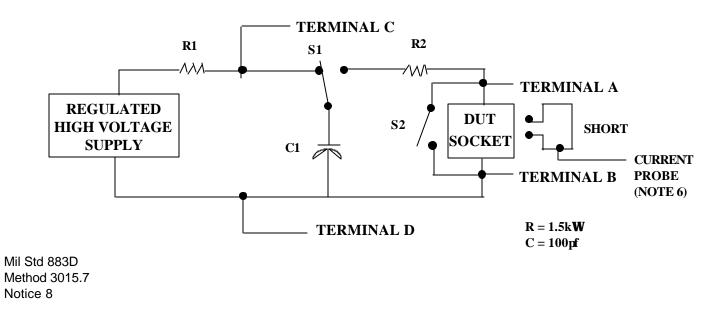
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V <sub>PS1</sub> <u>3/</u>	All V <sub>PS1</sub> pins
2.	All input and output pins	All other input-output pins

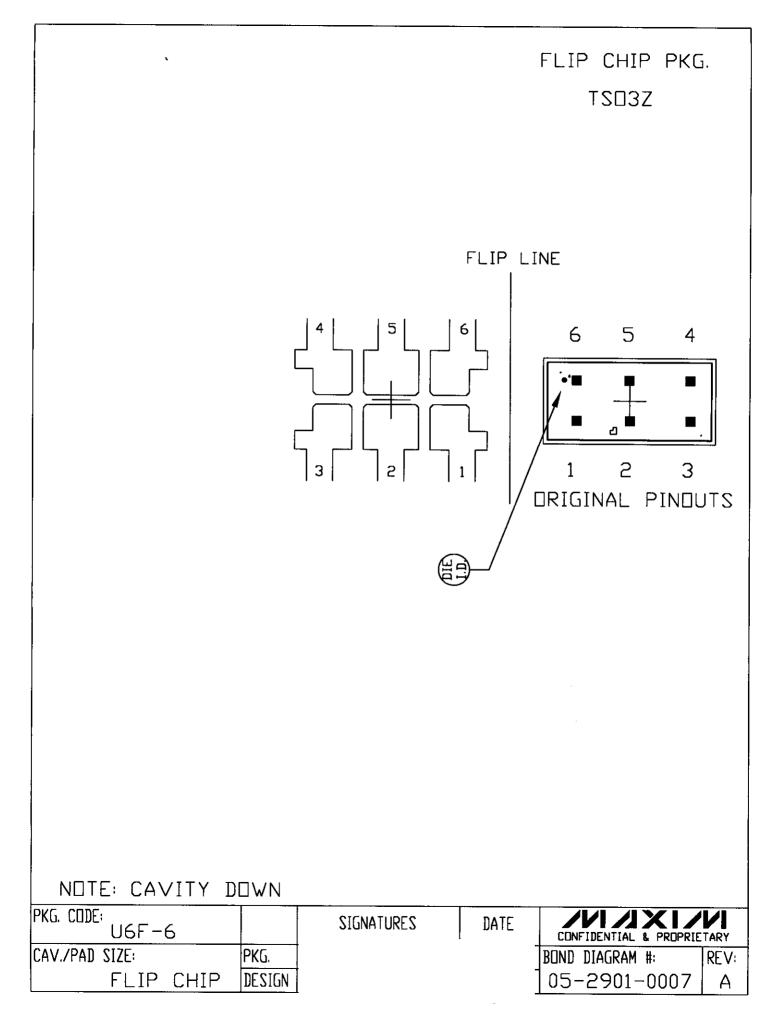
- 1/ Table II is restated in narrative form in 3.4 below.
- 2/ No connects are not to be tested.
- <u>3/</u> Repeat pin combination I for each named Power supply and for ground (e.g., where  $V_{PS1}$  is  $V_{DD}$ ,  $V_{CC}$ ,  $V_{SS}$ ,  $V_{BB}$ , GND,  $+V_{S}$ ,  $-V_{S}$ ,  $V_{REF}$ , etc).

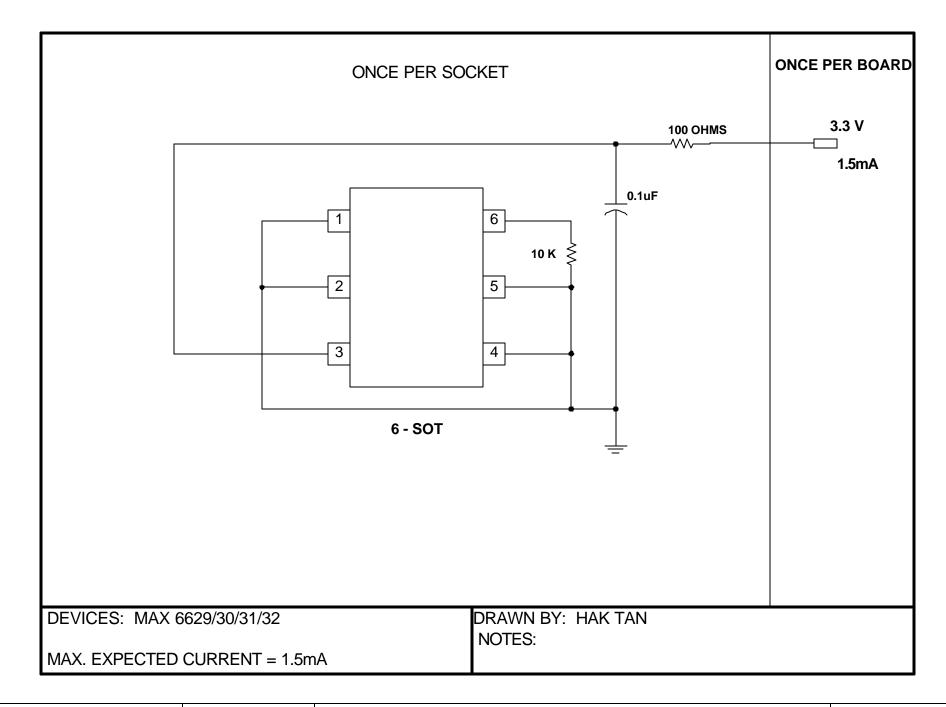
3.4 <u>Pin combinations to be tested.</u>

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g.,  $V_{SS1}$ , or  $V_{SS2}$  or  $V_{SS3}$  or  $V_{CC1}$ , or  $V_{CC2}$ ) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.

c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.







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